

Trans MOSFET N-CH 650V 34.6A 3-Pin(3+Tab) TO-247 Tube

Manufacturers	Infineon Technologies Corporation
Package/Case	TO-247
Product Type	Transistors
RoHS	
Lifecycle	



Images are for reference only

Please submit RFQ for SPW35N60C3 or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

SPW35N60C3 is a power MOSFET (Metal Oxide Semiconductor Field-Effect Transistor) manufactured by Infineon Technologies. Here are its features:

Features

Maximum Drain-Source Voltage (VDS): 600V

Continuous Drain Current (ID): 35A

Low On-Resistance (RDS(on)): 0.035 ohms

Fast Switching Characteristics

Avalanche Energy Rated

Application

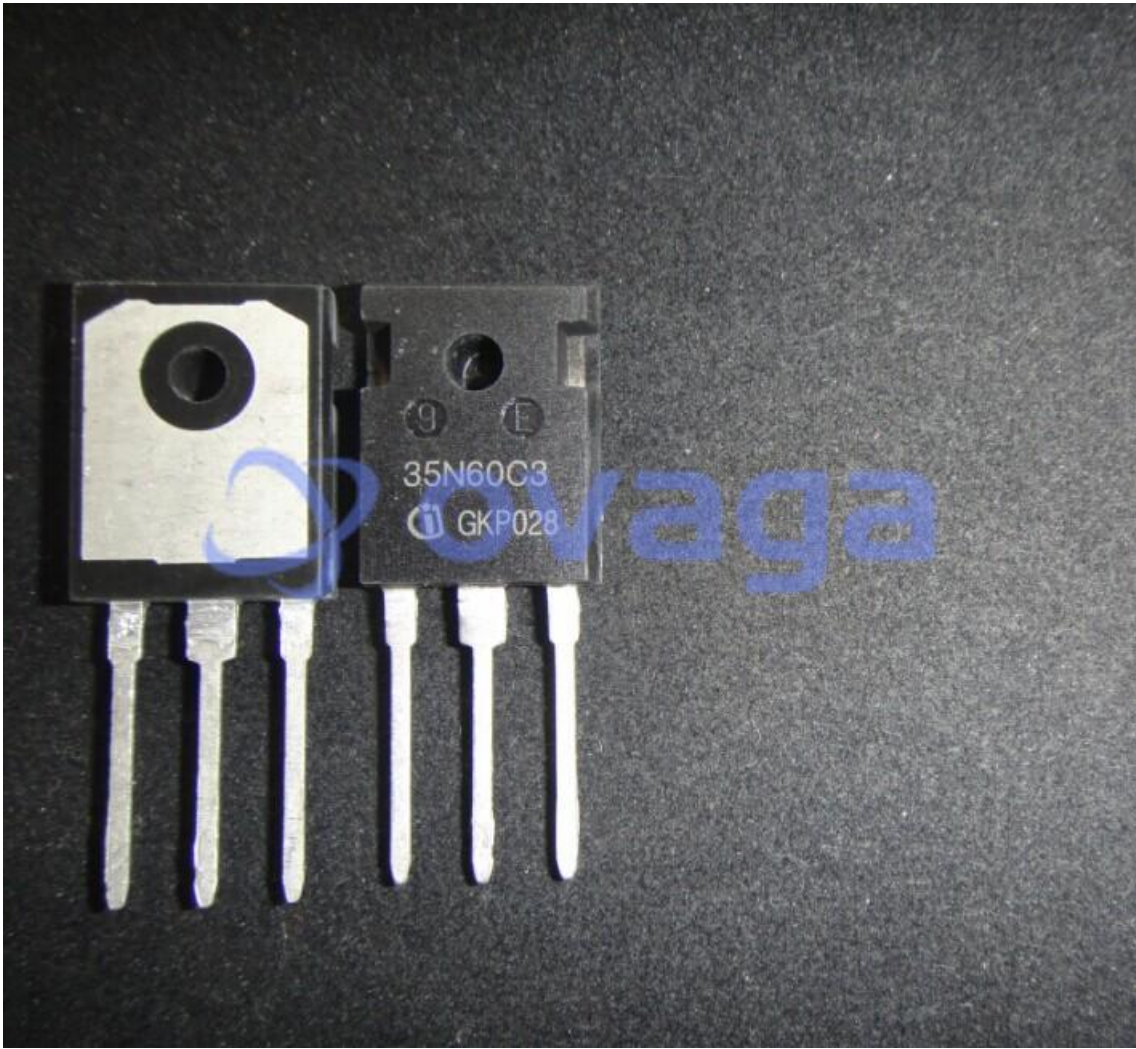
STW35N60M2 by STMicroelectronics

IRFP4768PBF by Infineon Technologies

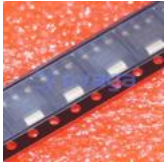
IXFH35N60Q by IXYS Corporation

RJK0355DPA by Renesas Electronics





Related Products



[BSP613P](#)

Infineon Technologies Corporation
SOT-223



[SPP11N65C3](#)

Infineon Technologies Corporation
TO-220



[SPP07N65C3](#)

Infineon Technologies Corporation
TO-220AB



[SPP07N60S5](#)

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P-TO220-3-1



[SPP11N60C3XKSA1](#)

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[IRF640NSPBF](#)

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[SPD03N60S5](#)

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TO-252



[SPP20N60CFD](#)

Infineon Technologies Corporation
TO-220AB